

# TRIAC (ISOLATED TYPE)

# TMG16C40/60F

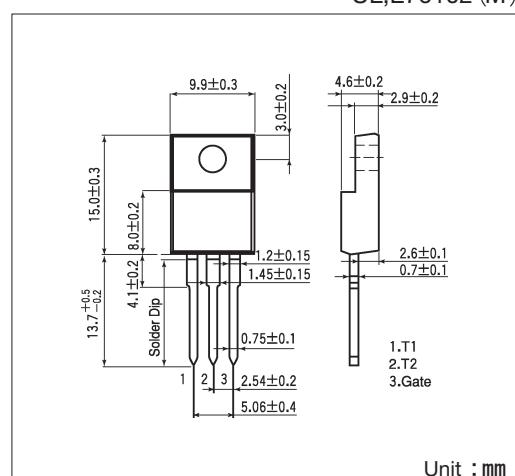
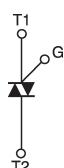
TOP



UL:E76102 (M)

**TMG16C40/60F** are isolated mold triac suitable for wide range of applications like copier, microwave oven, solid state switch, motor control, light and heater control.

- $I_T$  (RMS) 16A
- High surge capability 170A
- Full molded isolated type
- Three types of lead forming



Unit : mm

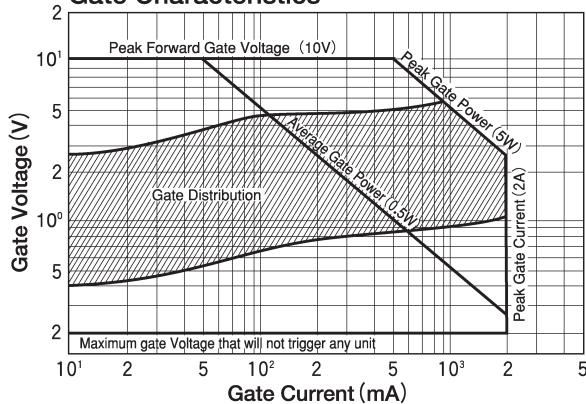
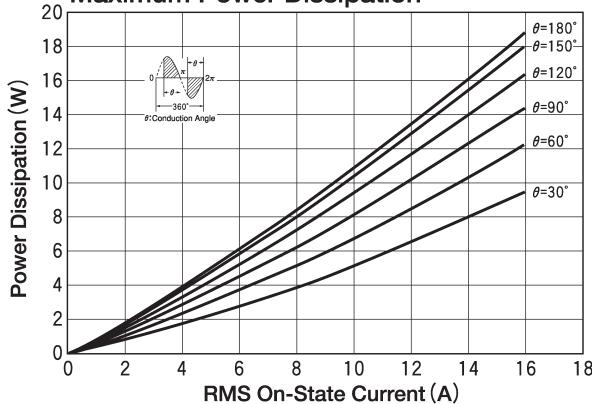
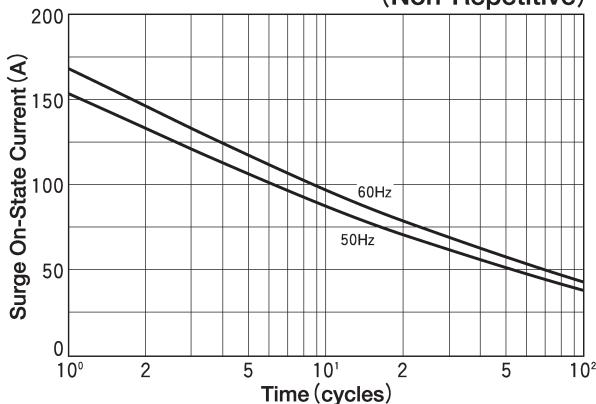
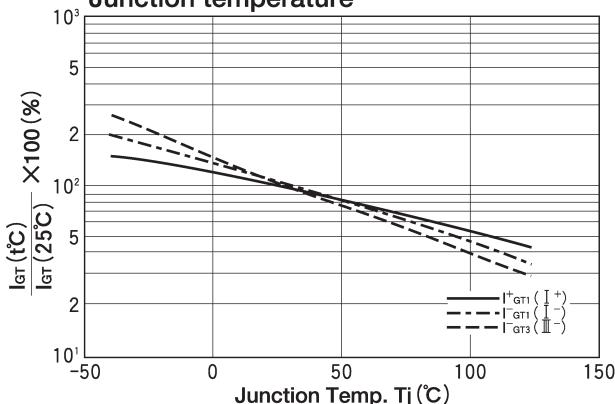
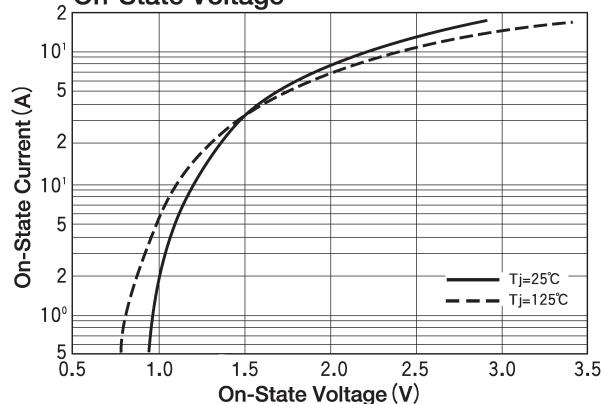
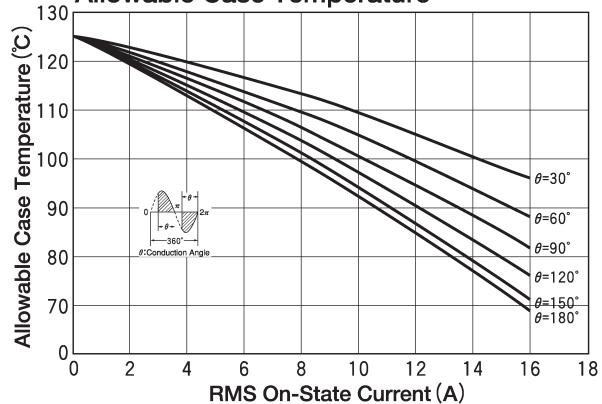
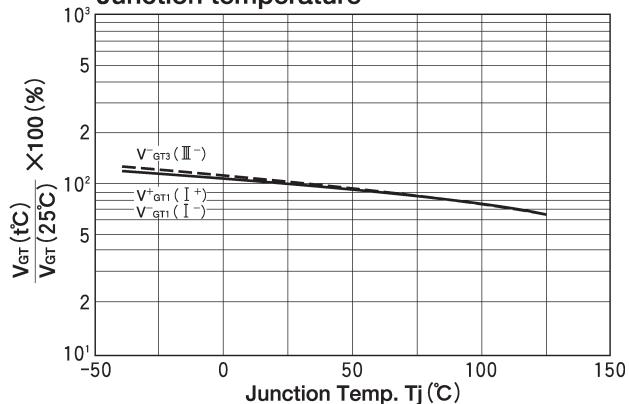
## ■ Maximum Ratings

Symbol	Item	Ratings		Unit
		TMG16C40F	TMG16C60F	
$V_{DRM}$	Repetitive Peak Off-State Voltage	400	600	V

Symbol	Item	Conditions	Ratings	Unit
$I_T$ (RMS)	R.M.S. On-State Current	$T_c=68^\circ\text{C}$	16	A
$I_{TSM}$	Surge On-State Current	One cycle, 50Hz/60Hz, peak, non-repetitive	155/170	A
$I^2t$	$I^2t$		120	$\text{A}^2\text{s}$
$P_{GM}$	Peak Gate Power Dissipation		5	W
$P_{G(AV)}$	Average Gate Power Dissipation		0.5	W
$I_{GM}$	Peak Gate Current		2	A
$V_{GM}$	Peak Gate Voltage		10	V
$V_{ISO}$	Isolation Breakdown Voltage (R.M.S.)	A.C. 1 minute	1500	V
$T_j$	Operating Junction Temperature		-40~+125	$^\circ\text{C}$
$T_{stg}$	Storage Temperature		-40~+125	$^\circ\text{C}$
	Mass		2	g

## ■ Electrical Characteristics

Symbol	Item	Conditions	Ratings			Unit
			Min.	Typ.	Max.	
$I_{DRM}$	Repetitive Peak Off-State Current	$V_D=V_{DRM}$ , Single phase, half wave, $T_j=125^\circ\text{C}$			2	mA
$V_{TM}$	Peak On-State Voltage	$I_T=25\text{A}$ , Inst. measurement			1.4	V
$I_{GT1}^+$ 1	Gate Trigger Current	$V_D=6\text{V}$ , $R_L=10\ \Omega$			30	mA
$I_{GT1}^-$ 2					30	
$I_{GT3}^+$ 3					—	
$I_{GT3}^-$ 4					30	
$V_{GT1}^+$ 1	Gate Trigger Voltage	$V_D=6\text{V}$ , $R_L=10\ \Omega$			1.5	V
$V_{GT1}^-$ 2					1.5	
$V_{GT3}^+$ 3					—	
$V_{GT3}^-$ 4					1.5	
$V_{GD}$	Non-Trigger Gate Voltage	$T_j=125^\circ\text{C}$ , $V_D=\frac{1}{2}V_{DRM}$	0.2			V
$(dv/dt)_c$	Critical Rate of Rise off-State Voltage at commutation	$T_j=125^\circ\text{C}$ , $(di/dt)_c=-8\text{A/ms}$ , $V_D=\frac{2}{3}V_{DRM}$	10			$\text{V}/\mu\text{s}$
$I_H$	Holding Current			25		mA
$R_{th(j-c)}$	Thermal Impedance	Junction to case			3.0	$^\circ\text{C}/\text{W}$

**Gate Characteristics****On State Current vs. Maximum Power Dissipation****Surge On-State Current Rating (Non-Repetitive)****Gate trigger current vs. Junction temperature****On-State Voltage****On State Current vs. Allowable Case Temperature****Gate trigger voltage vs. Junction temperature****Transient Thermal Impedance**